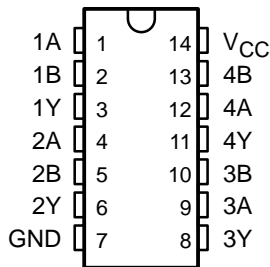


# SN54LV00A, SN74LV00A QUADRUPLE 2-INPUT POSITIVE-NAND GATES

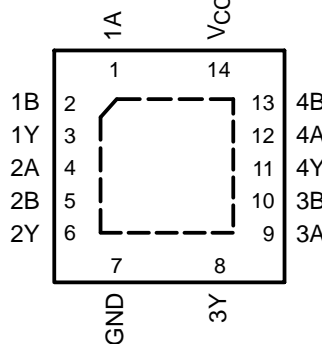
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- 2-V to 5.5-V  $V_{CC}$  Operation
- Max  $t_{pd}$  of 6.5 V at 5 V
- Typical  $V_{OLP}$  (Output Ground Bounce)  $<0.8$  V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$
- Typical  $V_{OHV}$  (Output  $V_{OH}$  Undershoot)  $>2.3$  V at  $V_{CC} = 3.3$  V,  $T_A = 25^\circ\text{C}$
- Support Mixed-Mode Voltage Operation on All Ports
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

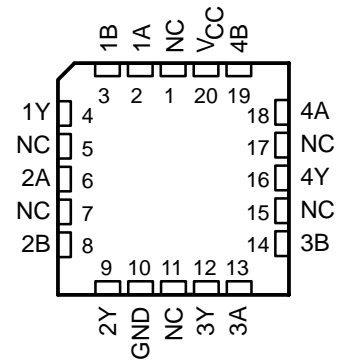
SN54LV00A . . . J OR W PACKAGE  
SN74LV00A . . . D, DB, DGV, NS,  
OR PW PACKAGE  
(TOP VIEW)



SN74LV00A . . . RGY PACKAGE  
(TOP VIEW)



SN54LV00A . . . FK PACKAGE  
(TOP VIEW)



NC – No internal connection

## description/ordering information

These quadruple 2-input positive-NAND gates are designed for 2-V to 5.5-V  $V_{CC}$  operation.

The 'LV00A devices perform the Boolean function  $Y = \overline{A \bullet B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

These devices are fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

## ORDERING INFORMATION

$T_A$	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RGY	Tape and reel	SN74LV00ARGYR	LV00A
	SOIC – D	Tube	SN74LV00AD	LV00A
		Tape and reel	SN74LV00ADR	
	SOP – NS	Tape and reel	SN74LV00ANSR	74LV00A
	SSOP – DB	Tape and reel	SN74LV00ADBR	LV00A
	TSSOP – PW	Tape and reel	SN74LV00APWR	LV00A
–55°C to 125°C	TVSOP – DGV	Tape and reel	SN74LV00ADGVR	LV00A
	CDIP – J	Tube	SNJ54LV00AJ	SNJ54LV00AJ
	CFP – W	Tube	SNJ54LV00AW	SNJ54LV00AW
	LCCC - FK	Tube	SNJ54LV00AFK	SNJ54LV00AFK

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).



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**TEXAS  
INSTRUMENTS**

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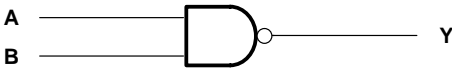
SN54LV00A, SN74LV00A  
QUADRUPLE 2-INPUT POSITIVE-NAND GATES

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FUNCTION TABLE  
(each gate)

INPUTS		OUTPUT
A	B	Y
H	H	L
L	X	H
X	L	H

logic diagram, each gate (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, $V_{CC}$	–0.5 V to 7 V
Input voltage range, $V_I$ (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high-impedance or power-off state, $V_O$ (see Note 1)	–0.5 V to 7 V
Output voltage range, $V_O$ (see Notes 1 and 2)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, $I_{IK}$ ( $V_I < 0$ )	–20 mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{CC}$ )	±50 mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )	±25 mA
Continuous current through $V_{CC}$ or GND	±50 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): D package	86°C/W
(see Note 3): DB package	96°C/W
(see Note 3): DGV package	127°C/W
(see Note 3): NS package	76°C/W
(see Note 3): PW package	113°C/W
(see Note 4): RGY package	47°C/W
Storage temperature range, $T_{stg}$	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
  2. This value is limited to 5.5 V maximum.
  3. The package thermal impedance is calculated in accordance with JESD 51-7.
  4. The package thermal impedance is calculated in accordance with JESD 51-5.

# SN54LV00A, SN74LV00A QUADRUPLE 2-INPUT POSITIVE-NAND GATES

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## recommended operating conditions (see Note 5)

			SN54LV00A		SN74LV00A		UNIT
			MIN	MAX	MIN	MAX	
V <sub>CC</sub>	Supply voltage		2	5.5	2	5.5	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 2 V	1.5		1.5		V
		V <sub>CC</sub> = 2.3 V to 2.7 V	V <sub>CC</sub> × 0.7		V <sub>CC</sub> × 0.7		
		V <sub>CC</sub> = 3 V to 3.6 V	V <sub>CC</sub> × 0.7		V <sub>CC</sub> × 0.7		
		V <sub>CC</sub> = 4.5 V to 5.5 V	V <sub>CC</sub> × 0.7		V <sub>CC</sub> × 0.7		
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 2 V		0.5		0.5	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		V <sub>CC</sub> × 0.3		V <sub>CC</sub> × 0.3	
		V <sub>CC</sub> = 3 V to 3.6 V		V <sub>CC</sub> × 0.3		V <sub>CC</sub> × 0.3	
		V <sub>CC</sub> = 4.5 V to 5.5 V		V <sub>CC</sub> × 0.3		V <sub>CC</sub> × 0.3	
V <sub>I</sub>	Input voltage		0	5.5	0	5.5	V
V <sub>O</sub>	Output voltage		0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 2 V		–50		–50	μA
		V <sub>CC</sub> = 2.3 V to 2.7 V		–2		–2	
		V <sub>CC</sub> = 3 V to 3.6 V		–6		–6	
		V <sub>CC</sub> = 4.5 V to 5.5 V		–12		–12	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2 V		50		50	μA
		V <sub>CC</sub> = 2.3 V to 2.7 V		2		2	
		V <sub>CC</sub> = 3 V to 3.6 V		6		6	
		V <sub>CC</sub> = 4.5 V to 5.5 V		12		12	
Δt/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 2.3 V to 2.7 V		200		200	ns/V
		V <sub>CC</sub> = 3 V to 3.6 V		100		100	
		V <sub>CC</sub> = 4.5 V to 5.5 V		20		20	
T <sub>A</sub>	Operating free-air temperature		–55	125	–40	85	°C

NOTE 5: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	SN54LV00A			SN74LV00A			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V <sub>OH</sub>	I <sub>OH</sub> = –50 μA	2 V to 5.5 V	V <sub>CC</sub> –0.1			V <sub>CC</sub> –0.1			V
	I <sub>OH</sub> = –2 mA	2.3 V	2			2			
	I <sub>OH</sub> = –6 mA	3 V	2.48			2.48			
	I <sub>OH</sub> = –12 mA	4.5 V	3.8			3.8			
V <sub>OL</sub>	I <sub>OL</sub> = 50 μA	2 V to 5.5 V			0.1			0.1	V
	I <sub>OL</sub> = 2 mA	2.3 V			0.4			0.4	
	I <sub>OL</sub> = 6 mA	3 V			0.44			0.44	
	I <sub>OL</sub> = 12 mA	4.5 V			0.55			0.55	
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V			±1			±1	μA
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	5.5 V			20			20	μA
I <sub>off</sub>	V <sub>I</sub> or V <sub>O</sub> = 0 to 5.5 V	0			5			5	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		3.3			3.3		pF
		5 V		3.3			3.3		

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# SN54LV00A, SN74LV00A

## QUADRUPLE 2-INPUT POSITIVE-NAND GATES

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**switching characteristics over recommended operating free-air temperature range,  $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$  (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN54LV00A		SN74LV00A		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$t_{pd}$	A	Y	$C_L = 15\text{ pF}$	7.1*	12.9*		1*	16*	1	15	ns
			$C_L = 50\text{ pF}$	9.6	16.6		1	21	1	20	

\* On products compliant to MIL-PRF-38535, this parameter is not production tested.

**switching characteristics over recommended operating free-air temperature range,  $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$  (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN54LV00A		SN74LV00A		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$t_{pd}$	A	Y	$C_L = 15\text{ pF}$		5*	7.9*	1*	10.5*	1	9.5	ns
			$C_L = 50\text{ pF}$		6.9	11.4	1	14	1	13	

\* On products compliant to MIL-PRF-38535, this parameter is not production tested.

**switching characteristics over recommended operating free-air temperature range,  $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$  (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN54LV00A		SN74LV00A		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$t_{pd}$	A	Y	$C_L = 15\text{ pF}$		3.6*	5.5*	1*	7.5*	1	6.5	ns
			$C_L = 50\text{ pF}$		4.9	7.5	1	9.5	1	8.5	

\* On products compliant to MIL-PRF-38535, this parameter is not production tested.

**noise characteristics,  $V_{CC} = 3.3\text{ V}$ ,  $C_L = 50\text{ pF}$ ,  $T_A = 25^\circ\text{C}$  (see Note 6)**

PARAMETER			SN74LV00A			UNIT
			MIN	TYP	MAX	
$V_{OL(P)}$	Quiet output, maximum dynamic $V_{OL}$			0.2	0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic $V_{OL}$			−0.1	−0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic $V_{OH}$			3.1		V
$V_{IH(D)}$	High-level dynamic input voltage		2.31			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.99		V

NOTE 6: Characteristics are for surface-mount packages only.

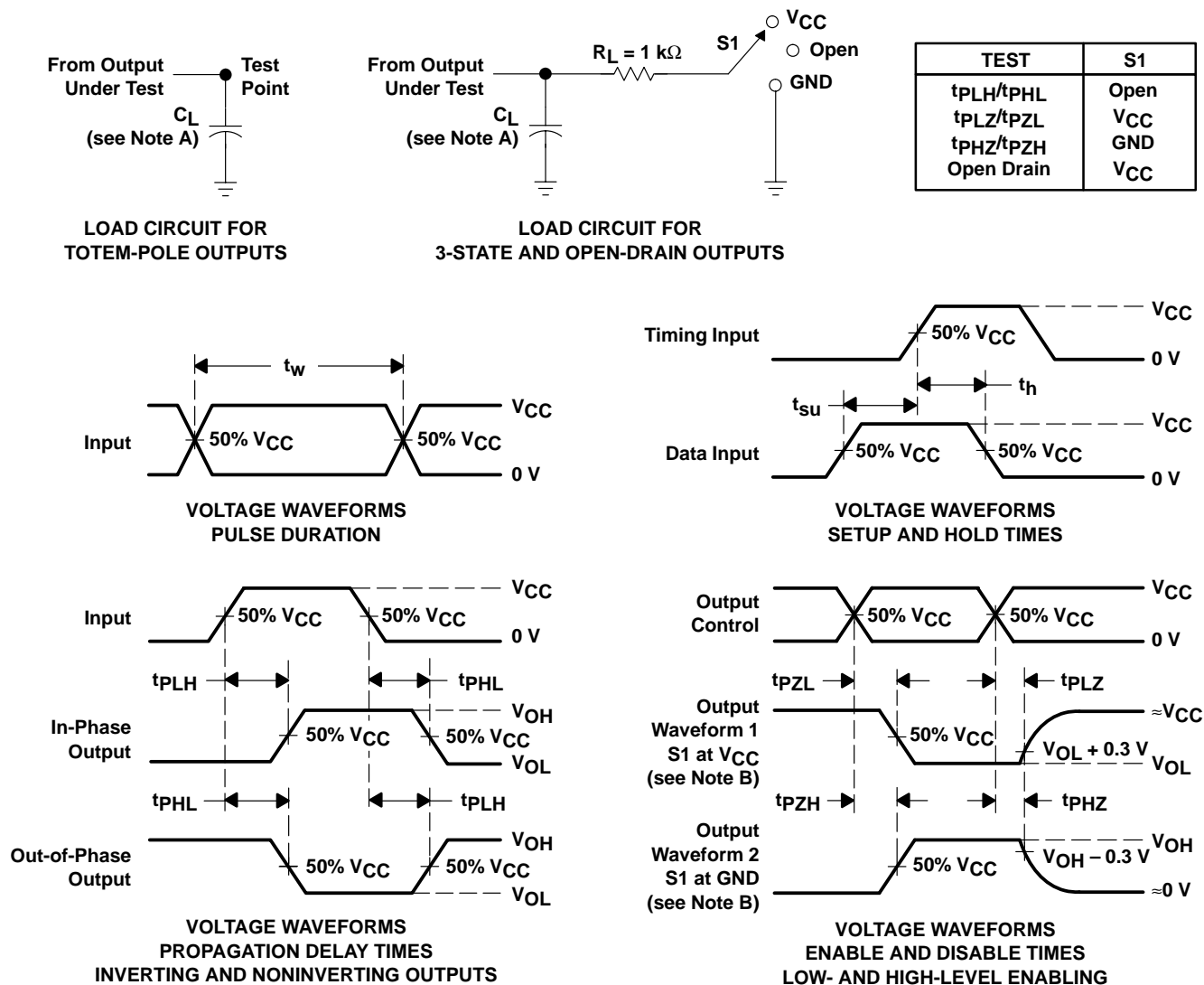
**operating characteristics,  $T_A = 25^\circ\text{C}$**

PARAMETER		TEST CONDITIONS		$V_{CC}$	TYP	UNIT
$C_{pd}$	Power dissipation capacitance	$C_L = 50\text{ pF}$ , $f = 10\text{ MHz}$		3.3 V	9.5	pF
				5 V	11	

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## PARAMETER MEASUREMENT INFORMATION



- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 1\text{ MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r \leq 3\text{ ns}$ ,  $t_f \leq 3\text{ ns}$ .
  - D. The outputs are measured one at a time with one input transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PHL}$  and  $t_{PLH}$  are the same as  $t_{pd}$ .
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

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Mailing Address:

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Dallas, Texas 75265